

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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The logo for Renesas, featuring the word "RENESAS" in a bold, sans-serif font. The letter "R" is stylized with a square dot at its top-left corner.

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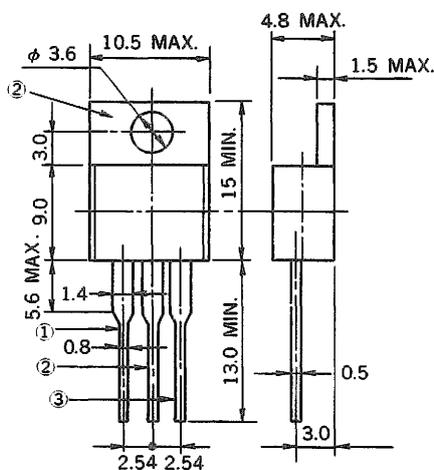
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8 A(12 A<sub>r.m.s.</sub>) THYRISTOR

PACKAGE DIMENSIONS  
in millimeters



Pin Connection  
 ① Cathode  
 ② Anode  
 ③ Gate

The 8P2M and 8P4M are P gate all diffused mold type Thyristor granted 8 Amp On-state Average Current ( $T_c = 90^\circ\text{C}$ ), with voltages up to 400 volts.

FEATURES

- Easy installation by TO-220 AB package.
- 100 A surge current.
- High Voltage.
  - :  $V_{DRM}, V_{RRM} = 200\text{ V}$  (8P2M)
  - :  $V_{DRM}, V_{RRM} = 400\text{ V}$  (8P4M)

APPLICATIONS

- Motor speed control for household appliance.
- Temperature control for heater and constant temperature box.
- Constant voltage power source and battery charger.
- Automotive application such as regulator.
- Various solid state relay etc.

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	8P2M	8P4M	UNIT	NOTE
Non-Repetitive Peak Reverse Voltage	$V_{RSM}$	300	500	V	
Non-Repetitive Peak Off-State Voltage	$V_{DSM}$	300	500	V	
Repetitive Peak Reverse Voltage	$V_{RRM}$	200	400	V	
Repetitive Peak Off-State Voltage	$V_{DRM}$	200	400	V	
Average On-State Current	$I_T(AV)$	8 ( $T_c = 90^\circ\text{C}, \theta = 180^\circ$ Single phase half wave)		A	See Fig. 11
Surge On-State Current	$I_{TSM}$	100		A	See Fig. 2
Fusing Current	$\int i^2 dt$	45 ( $1\text{ ms} \leq t \leq 10\text{ ms}$ )		$A^2s$	
Peak Gate Power Dissipation	$P_{GM}$	5 ( $f \geq 50\text{ Hz}, \text{Duty} \leq 10\%$ )		W	See Fig. 3
Average Gate Power Dissipation	$P_{G(AV)}$	0.5		W	
Peak Gate Forward Current	$I_{FGM}$	2 ( $f \geq 50\text{ Hz}, \text{Duty} \leq 10\%$ )		A	
Peak Gate Reverse Voltage	$V_{RGM}$	10		V	
Junction Temperature	$T_j$	-40 to +125		$^\circ\text{C}$	
Storage Temperature	$T_{stg}$	-55 to +150		$^\circ\text{C}$	
Weight		2		g	

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ELECTRICAL CHARACTERISTICS (T<sub>j</sub> = 25 °C)

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT	NOTE
Repetitive Peak Reverse Current	I <sub>R</sub> RM	V <sub>RM</sub> = V <sub>R</sub> RM, T <sub>j</sub> = 125 °C	—	—	2	mA	
Repetitive Peak Off-State Current	I <sub>D</sub> RM	V <sub>DM</sub> = V <sub>D</sub> RM, T <sub>j</sub> = 125 °C	—	—	2	mA	
On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 25 A	—	—	1.4	V	See Fig. 1
Gate-Trigger Current	I <sub>GT</sub>	V <sub>DM</sub> = 6 V, R <sub>L</sub> = 100 Ω	—	—	10	mA	See Fig. 4
Gate-Trigger Voltage	V <sub>GT</sub>	V <sub>DM</sub> = 6 V, R <sub>L</sub> = 100 Ω	—	—	1.5	V	
Gate Non-Trigger Voltage	V <sub>GD</sub>	V <sub>DM</sub> = 1/2 V <sub>D</sub> RM, T <sub>j</sub> = 125 °C	0.2	—	—	V	
Critical Rate of Rise of Off-State Voltage	dv/dt	V <sub>DM</sub> = V <sub>D</sub> RM, T <sub>j</sub> = 125 °C	—	40	—	V/μs	
Holding Current	I <sub>H</sub>	V <sub>D</sub> = 24 V	—	6	—	mA	
Circuit Commuted Turn-Off Time	t <sub>q</sub>	I <sub>TM</sub> = 5 A, V <sub>R</sub> ≥ 25 V V <sub>DM</sub> = 2/3 V <sub>D</sub> RM, di <sub>R</sub> /dt = 15 A/μs dv/dt = 10 V/μs, T <sub>j</sub> = 125 °C	—	100	—	μs	
Thermal Resistance	R <sub>th</sub>	Junction to case	—	—	3	°C/W	See Fig. 13

Fig. 1 I<sub>T</sub> - V<sub>T</sub> CHARACTERISTIC

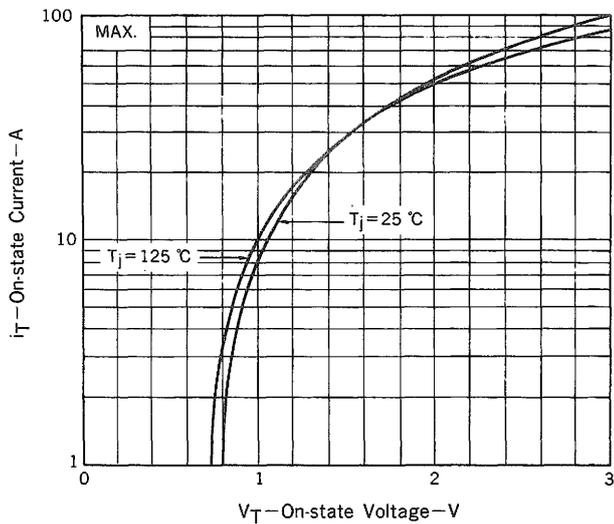


Fig. 2 I<sub>TSM</sub> RATING

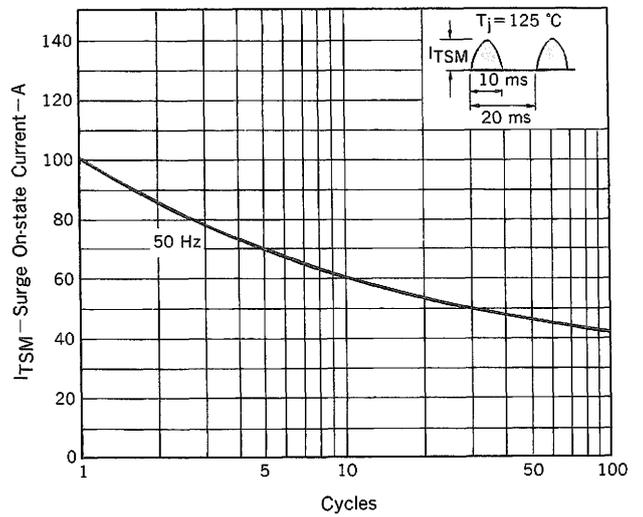


Fig. 3 GATE POWER RATING

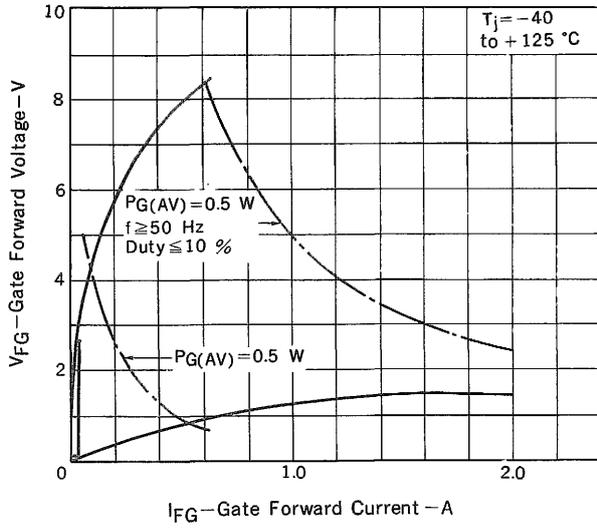


Fig. 4 I<sub>GT</sub> - V<sub>GT</sub> DISTRIBUTION

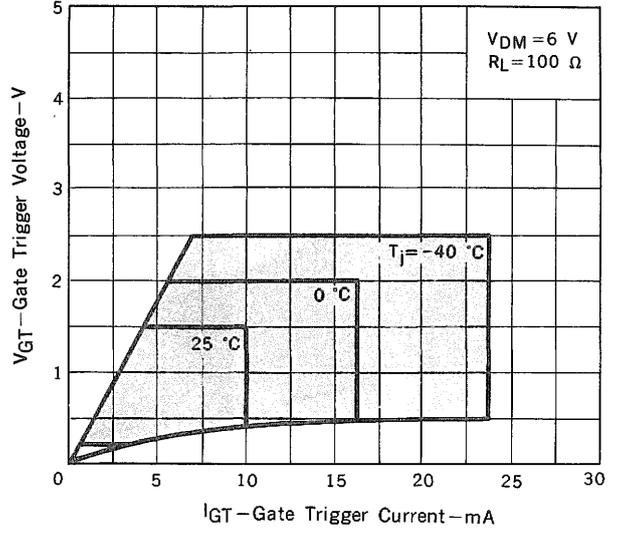


Fig. 5 I<sub>GT</sub> - T<sub>a</sub> TYPICAL DISTRIBUTION

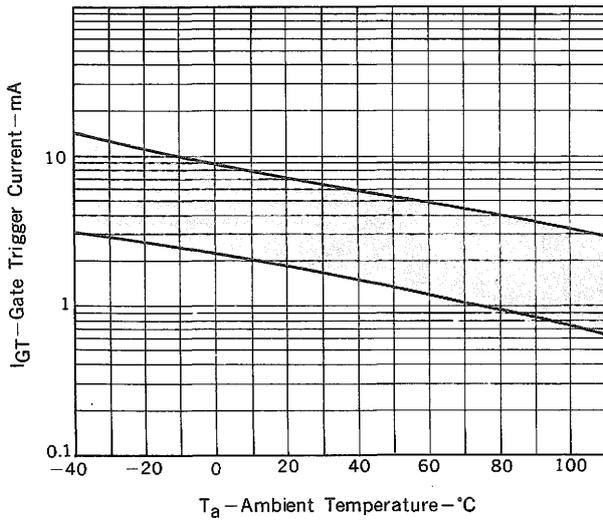


Fig. 6 V<sub>GT</sub> - T<sub>a</sub> TYPICAL DISTRIBUTION

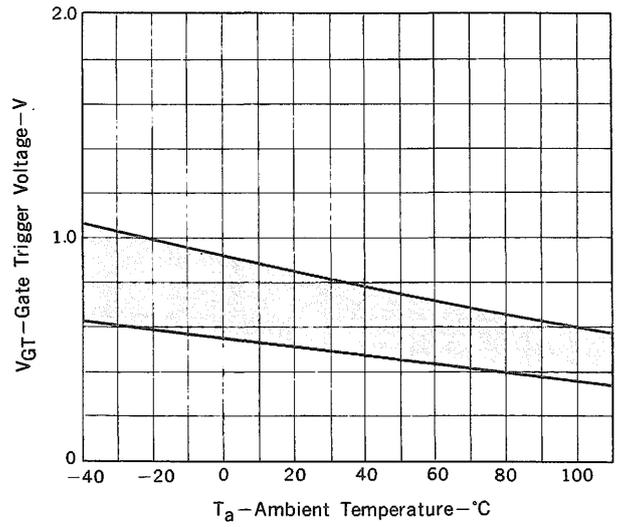


Fig. 7 i<sub>GS</sub> - τ<sub>G</sub> TYPICAL DISTRIBUTION

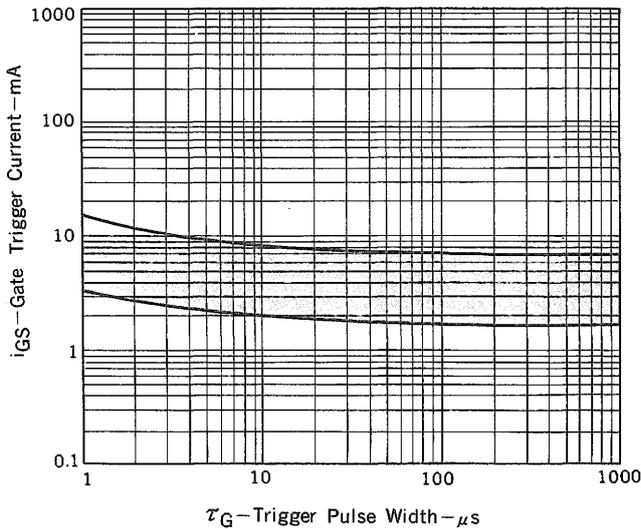


Fig. 8 V<sub>GT</sub> - τ<sub>G</sub> TYPICAL DISTRIBUTION

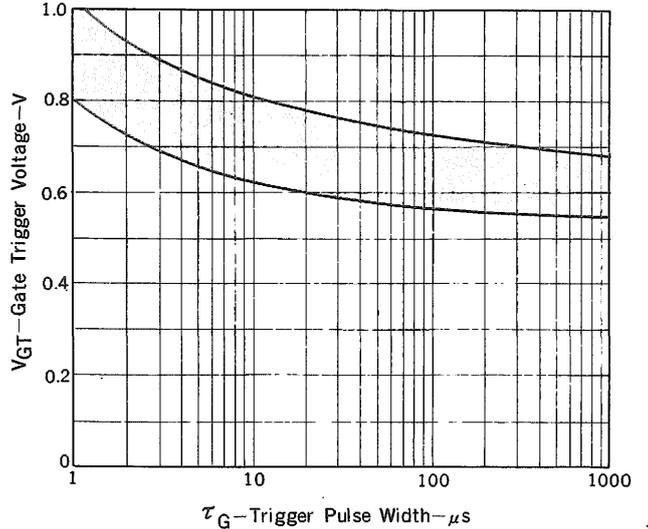


Fig. 9  $I_H - T_a$  TYPICAL DISTRIBUTION

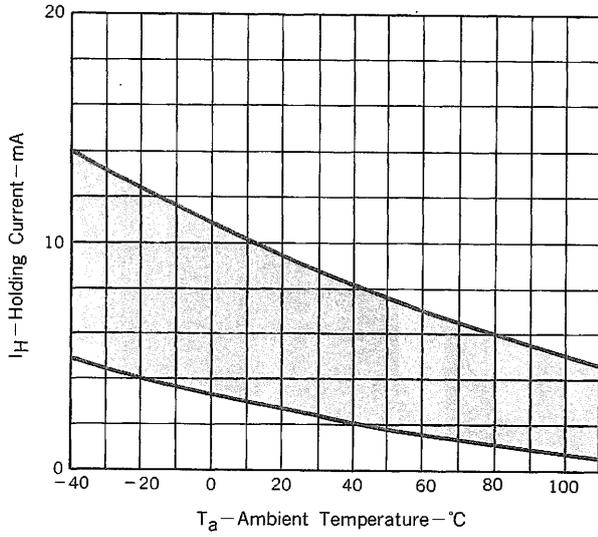


Fig. 10  $P_T(AV) - I_T(AV)$  CHARACTERISTICS

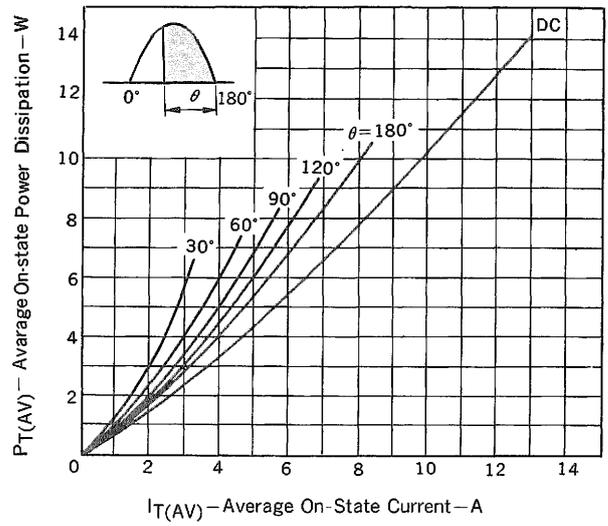


Fig. 11  $T_c - I_T(AV)$  RATING

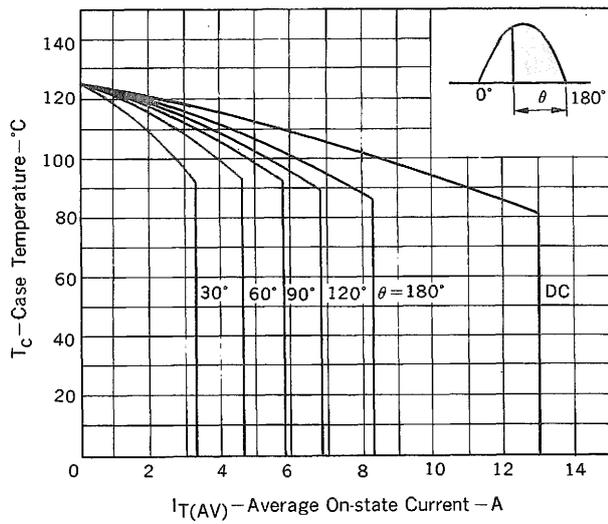


Fig. 12  $T_a - I_T(AV)$  RATING

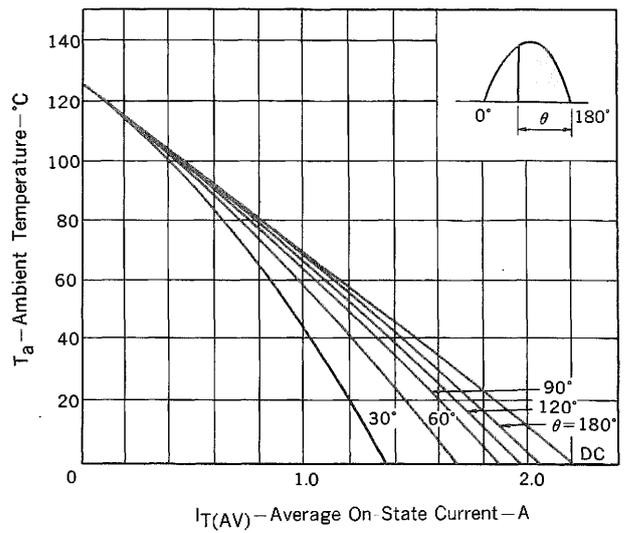


Fig. 13  $Z_{th}$  CHARACTERISTICS

